IBM Docket: BUR920030058US1 SSM&P Docket: 16693

Declaration and Power of Attorney for Patent Application

As a below named inventor, I hereby declare that:

the specification of which (check one)

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled: HIGH TOLERANCE TCR BALANCED HIGH CURRENT RESISTOR FOR RF CMOS AND RF SIGE BICMOS APPLICATIONS AND CADENCED BASED HIERARCHICAL PARAMETERIZED CELL DESIGN KIT WITH TUNABLE TCR AND ESD RESISTOR BALLASTING FEATURE

x	is attached hereto.			
	was filed on	as	Application Serial No.	and was amended on
I hereby state to amended by any	that I have reviewed and amendment referred to a	understand the content bove.	ts of the above- identified s	specification, including the claims, as
I acknowledge the Code of Federal	ne duty to disclose informa Regulations, §1.56.	ation which is material t	o the patentability of this ap	pplication in accordance with Title 37
certificate listed	oreign priority benefits und d below and have also iden ne application on which pr	tified below any foreign	tes Code, §119 of any foreign application for patent or inv	n application(s) for patent or inventor's ventor's certificate having a filing date
Prior F	Foreign Application(s):			
Numbe	er Co	ountry	Day/Month/Year	Priority Claimed
the first paragra of this application	of each of the claims of this ph of Title 35, United State	application is not disclors Ses Code, §112, I acknow Code of Federal Regula	osed in the prior United State ledge the duty to disclose inf ations, §1.56 which occurred	ation(s) listed below and, insofar as the es application in the manner provided by formation material to the patentability d between the filing date of the prior
Prior U	J.S. Applications:			
Serial	No.	Filing Date		Status
like so made are	ed to be true; and further to punishable by fine or impi	that these statements w risonment, or both, und	ere made with the knowledg	statements made on information and ge that willful false statements and the f the United States Code and that such pereon.
Richard A. Henkle No. 27,465); Rob Redmond, Jr. (Re	Trademark Office connect er, Reg. No. 39,220; Richar bert A. Walsh (Reg. No. 26, eg. No. 18,753); Steven Fi h L. King (Reg. No. 24,223);	ed therewith: Anthony d M. Kotulak (Reg. No. 2 516); Christopher A. Hu schman (Reg. No. 34,59	r Canale, Reg. No. 51,526; A 27,712); Michael LeStrange (I 1ghes (Reg. No. 26,914); John 14); Leopold Presser, (Reg. N	application and transact all business in Mark F. Chadurjian (Reg. No. 30,739); Reg. No. 53,207); William D. Sabo (Reg. n E. Hoel (Reg. No. 26,279); Joseph C. o. 19,827); Frank S. DiGiglio (Reg. No. Reg. No. 39,394) and Edward W. Grolz

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Declaration and Power of Attorney for Patent Application

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